

CMOS Digital Integrated Circuits Silicon Monolithic

# 74HC573D

### 1. Functional Description

· Octal D-Type Latch with 3-State Outputs

#### 2. General

The 74HC573D is a high speed CMOS OCTAL LATCH with 3-STATE OUTPUT fabricated with silicon gate C2MOS technology.

It achieves the high speed operation similar to equivalent LSTTL while maintaining the CMOS low power dissipation.

These 8-bit D-type latch is controlled by a latch enable input (LE) and an output enable input (OE).

When the OE input is high, the eight outputs are in a high impedance state.

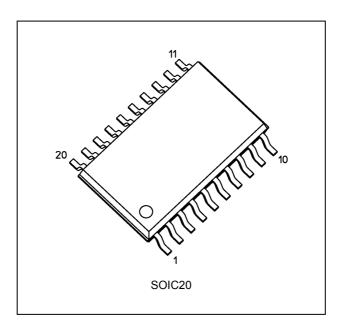
All inputs are equipped with protection circuits against static discharge or transient excess voltage.

#### 3. Features

- (1) Wide operating temperature range:  $T_{opr} = -40$  to 125 °C (Note 1)
- (2) High speed:  $t_{pd} = 13 \text{ ns (typ.)}$  at  $V_{CC} = 6.0 \text{ V}$
- (3) Low power dissipation:  $I_{CC} = 4.0 \mu A \text{ (max)}$  at  $T_a = 25 \text{ °C}$
- (4) Balanced propagation delays: t<sub>PLH</sub> ≈ t<sub>PHL</sub>
- (5) Wide operating voltage range:  $V_{CC(opr)} = 2.0 \text{ V}$  to 6.0 V

Note 1: Operating Range spec of  $T_{opr}$  = -40 °C to 125 °C is applicable only for the products which manufactured after July 2020.

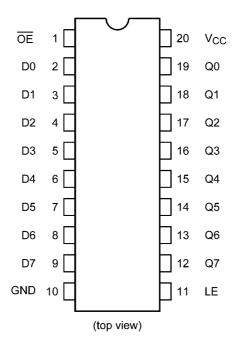
### 4. Packaging



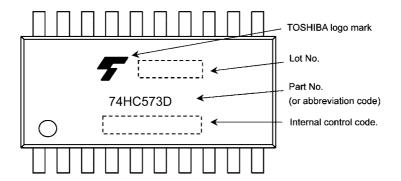
Start of commercial production



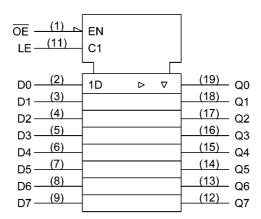
## 5. Pin Assignment



## 6. Marking



## 7. IEC Logic Symbol





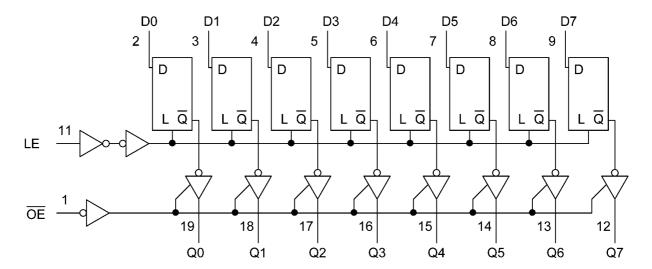
### 8. Truth Table

INPUT OE	INPUT LE	INPUT D	OUTPUT Q
Н	Х	Х	Z
L	L	Х	Qn
L	Н	L	L
L	Н	Н	Н

X: Don't CareZ: High Impedance

Qn: Q outputs are latched at the time when the LE input is taken to low logic level.

## 9. System Diagram





## 10. Absolute Maximum Ratings (Note)

Characteristics	Symbol	Note	Rating	Unit
Supply voltage	V <sub>CC</sub>		-0.5 to 7.0	V
Input voltage	V <sub>IN</sub>		-0.5 to V <sub>CC</sub> + 0.5	V
Output voltage	V <sub>OUT</sub>		-0.5 to V <sub>CC</sub> + 0.5	V
Input diode current	I <sub>IK</sub>		±20	mA
Output diode current	I <sub>OK</sub>		±20	mA
Output current	I <sub>OUT</sub>		±35	mA
V <sub>CC</sub> /ground current	I <sub>CC</sub>		±75	mA
Power dissipation	P <sub>D</sub>	(Note 1)	500	mW
Storage temperature	T <sub>stg</sub>		-65 to 150	°C

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: P<sub>D</sub> derates linearly with -8 mW/°C above 85 °C

## 11. Operating Ranges (Note)

Characteristics	Symbol	Note	Test Condition	Rating	Unit
Supply voltage	V <sub>CC</sub>			2.0 to 6.0	V
Input voltage	$V_{IN}$		I	0 to V <sub>CC</sub>	V
Output voltage	V <sub>OUT</sub>		I	0 to V <sub>CC</sub>	V
Operating temperature	$T_{opr}$	(Note 1)		-40 to 125	°C
Input rise and fall times	t <sub>r</sub> ,t <sub>f</sub>		V <sub>CC</sub> = 2.0 V	0 to 1000	ns
			V <sub>CC</sub> = 4.5 V	0 to 500	
			V <sub>CC</sub> = 6.0 V	0 to 400	
		(Note 1)		0 to 50	μS

Note: The operating ranges must be maintained to ensure the normal operation of the device. Unused inputs must be tied to either  $V_{CC}$  or GND.

Note 1: Operating Range spec of  $T_{opr}$  = -40 °C to 125 °C is applicable only for the products which manufactured after July 2020.



### 12. Electrical Characteristics

# 12.1. DC Characteristics (Unless otherwise specified, $T_a = 25$ °C)

Characteristics	Symbol	Test Condition		V <sub>CC</sub> (V)	Min	Тур.	Max	Unit
High-level input voltage	V <sub>IH</sub>	_	_		1.50	_	_	V
				4.5	3.15	_	_	V
				6.0	4.20	_		V
Low-level input voltage	V <sub>IL</sub>	_		2.0		_	0.50	V
				4.5			1.35	V
				6.0		_	1.80	V
High-level output voltage	V <sub>OH</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OH</sub> = -20 μA	2.0	1.9	2.0	_	V
				4.5	4.4	4.5		
				6.0	5.9	6.0	_	
			I <sub>OH</sub> = -6 mA	4.5	4.18	4.31	_	
			I <sub>OH</sub> = -7.8 mA	6.0	5.68	5.80	_	
Low-level output voltage	V <sub>OL</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OL</sub> = 20 μA	2.0	_	0.0	0.1	V
				4.5	_	0.0	0.1	
				6.0	_	0.0	0.1	
			I <sub>OL</sub> = 6 mA	4.5	_	0.17	0.26	
			I <sub>OL</sub> = 7.8 mA	6.0	_	0.18	0.26	V
3-state output OFF-state leakage current	I <sub>OZ</sub>	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{OUT} = V_{CC} \text{ or GND}$		6.0	_	_	±0.5	μА
Input leakage current	I <sub>IN</sub>	$V_{IN} = V_{CC}$ or GND		6.0		_	±0.1	μА
Quiescent supply current	Icc	$V_{IN} = V_{CC}$ or GND $I_{O} = 0$ A		6.0	_	_	4.0	μА

# 12.2. DC Characteristics (Unless otherwise specified, $T_a$ = -40 to 85 °C)

Characteristics	Symbol	Test Condition	1	V <sub>CC</sub> (V)	Min	Max	Unit
High-level input voltage	V <sub>IH</sub>	_		2.0	1.50	_	V
				4.5	3.15	_	
				6.0	4.20	_	V
Low-level input voltage	V <sub>IL</sub>	_		2.0	_	0.50	V
				4.5		1.35	
				6.0		1.80	V
High-level output voltage	V <sub>OH</sub>	$V_{IN} = V_{IH}$ or $V_{IL}$	I <sub>OH</sub> = -20 μA	2.0	1.9	_	V
				4.5	4.4	_	
				6.0	5.9	_	
			I <sub>OH</sub> = -6 mA	4.5	4.13	_	
			I <sub>OH</sub> = -7.8 mA	6.0	5.63	_	
Low-level output voltage	V <sub>OL</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OL</sub> = 20 μA	2.0	_	0.1	V
				4.5	_	0.1	
				6.0	_	0.1	
			I <sub>OL</sub> = 6 mA	4.5	_	0.33	
			I <sub>OL</sub> = 7.8 mA	6.0	_	0.33	V
3-state output OFF-state leakage current	I <sub>OZ</sub>	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{OUT} = V_{CC} \text{ or GND}$		6.0	_	±5.0	μА
Input leakage current	I <sub>IN</sub>	$V_{IN} = V_{CC}$ or GND		6.0		±1.0	μА
Quiescent supply current	I <sub>CC</sub>	$V_{IN} = V_{CC}$ or GND $I_O = 0$ A		6.0	_	40.0	μА



## 12.3. DC Characteristics (Note) (Unless otherwise specified, T<sub>a</sub> = -40 to 125 °C)

Characteristics	Symbol	Test Condition	ı	V <sub>CC</sub> (V)	Min	Max	Unit
High-level input voltage	V <sub>IH</sub>	_		2.0	1.50	_	V
				4.5	3.15	_	
				6.0	4.20	_	
Low-level input voltage	V <sub>IL</sub>	_		2.0		0.50	V
				4.5		1.35	
				6.0	_	1.80	V
High-level output voltage	V <sub>OH</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OH</sub> = -20 μA	2.0	1.9	_	V
				4.5	4.4	_	
				6.0	5.9	_	
			I <sub>OH</sub> = -6 mA	4.5	3.7	_	]
			I <sub>OH</sub> = -7.8 mA	6.0	5.2	_	
Low-level output voltage	V <sub>OL</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OL</sub> = 20 μA	2.0	_	0.1	V
				4.5	_	0.1	
				6.0	_	0.1	
			I <sub>OL</sub> = 6 mA	4.5	_	0.4	
			I <sub>OL</sub> = 7.8 mA	6.0	_	0.4	V
3-state output OFF-state leakage current	l <sub>OZ</sub>	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{OUT} = V_{CC} \text{ or GND}$		6.0	_	±5.0	μА
Input leakage current	I <sub>IN</sub>	$V_{IN} = V_{CC}$ or GND		6.0	_	±1.0	μА
Quiescent supply current	I <sub>CC</sub>	$V_{IN} = V_{CC}$ or GND $I_{O} = 0A$		6.0	_	80.0	μА

Note: Operating Range spec of  $T_{opr}$  = -40 °C to 125 °C is applicable only for the products which manufactured after July 2020.



# 12.4. Timing Requirements (Unless otherwise specified, $T_a$ = 25 °C, Input: $t_r$ = $t_f$ = 6 ns)

Characteristics	Symbol	Test Condition	V <sub>CC</sub> (V)	Limit	Unit
Minimum pulse width	t <sub>w(H)</sub>	_	2.0	75	ns
(LE)			4.5	15	
			6.0	13	
Minimum setup time	ts	_	2.0	50	ns
			4.5	10	
			6.0	9	
Minimum hold time	t <sub>h</sub>	_	2.0	5	ns
			4.5	5	
			6.0	5	

# 12.5. Timing Requirements (Unless otherwise specified, $T_a = -40$ to 85 °C, Input: $t_r = t_f = 6$ ns)

Characteristics	Symbol	Test Condition	V <sub>CC</sub> (V)	Limit	Unit
Minimum pulse width	t <sub>w(H)</sub>	_	2.0	95	ns
(LE)			4.5	19	
			6.0	16	
Minimum setup time	t <sub>s</sub>	_	2.0	65	ns
			4.5	13	
			6.0	11	
Minimum hold time	t <sub>h</sub>	_	2.0	5	ns
			4.5	5	
			6.0	5	

# 12.6. Timing Requirements (Note) (Unless otherwise specified, $T_a$ = -40 to 125 °C, Input: $t_r$ = $t_f$ = 6 ns)

Characteristics	Symbol	Test Condition	V <sub>CC</sub> (V)	Limit	Unit
Minimum pulse width	t <sub>w(H)</sub>	_	2.0	108	ns
(LE)			4.5	22	
			6.0	18	
Minimum setup time	ts	_	2.0	75	ns
			4.5	15	
			6.0	12	
Minimum hold time	t <sub>h</sub>	_	2.0	5	ns
			4.5	5	
			6.0	5	

Note : Operating Range spec of  $T_{opr}$  = -40 °C to 125 °C is applicable only for the products which manufactured after July 2020.



## 12.7. AC Characteristics (Unless otherwise specified, $T_a = 25$ °C, Input: $t_r = t_f = 6$ ns)

Characteristics	Symbol	Note	Test Condition	V <sub>CC</sub> (V)	C <sub>L</sub> (pF)	Min	Тур.	Max	Unit
Output transition time	t <sub>TLH</sub> ,t <sub>THL</sub>		_	2.0	50	_	20	60	ns
				4.5	]	_	6	12	
				6.0		_	5	10	
Propagation delay time	t <sub>PLH</sub> ,t <sub>PHL</sub>		_	2.0	50	_	50	115	ns
(LE-Q)				4.5	] [	_	15	23	
				6.0			13	20	
				2.0	150	_	60	155	ns
				4.5	] [	_	20	31	
				6.0		_	17	26	
Propagation delay time	t <sub>PLH</sub> ,t <sub>PHL</sub>		_	2.0	50	_	42	110	ns
(D-Q)				4.5	] [	_	14	22	
				6.0			12	19	
				2.0	150	_	57	150	ns
				4.5			19	30	
				6.0		_	16	26	
Output enable time	t <sub>PZL</sub> ,t <sub>PZH</sub>		$R_L = 1 k\Omega$	2.0	50	_	55	140	ns
				4.5	] [	_	17	28	
				6.0		_	14	24	
				2.0	150	_	66	180	ns
				4.5		_	22	36	
				6.0		_	19	31	
Output disable time	$t_{PLZ}, t_{PHZ}$		$R_L = 1 k\Omega$	2.0	50	_	40	125	ns
				4.5			17	25	
				6.0		_	15	21	
Input capacitance	C <sub>IN</sub>					_	5	10	pF
Output capacitance	C <sub>OUT</sub>					_	10	_	pF
Power dissipation capacitance	C <sub>PD</sub>	(Note 1)	_			_	51	_	pF

Note 1: C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation.

 $I_{CC(opr)} = C_{PD} \times V_{CC} \times f_{IN} + I_{CC}/8$  (per latch)

And the total C<sub>PD</sub> when n pcs. of latch operate can be gained by the following equation:

 $C_{PD}$  (total) = 33 + 18 × n



# 12.8. AC Characteristics (Unless otherwise specified, $T_a = -40$ to 85 °C, Input: $t_r = t_f = 6$ ns)

Characteristics	Symbol	Test Condition	V <sub>CC</sub> (V)	C <sub>L</sub> (pF)	Min	Max	Unit
Output transition time	t <sub>TLH</sub> ,t <sub>THL</sub>	_	2.0	50	_	75	ns
			4.5		_	15	
			6.0		_	13	
Propagation delay time	t <sub>PLH</sub> ,t <sub>PHL</sub>	_	2.0	50	_	145	ns
(LE-Q)			4.5			29	
			6.0		_	25	
			2.0	150	_	195	ns
			4.5		_	39	
			6.0	]	_	33	
Propagation delay time (D-Q)	t <sub>PLH</sub> ,t <sub>PHL</sub>	_	2.0	50	_	140	ns
			4.5		_	28	
			6.0		_	24	
			2.0	150	_	190	ns
			4.5			38	
			6.0		_	32	
Output enable time	$t_{PZL}, t_{PZH}$	R <sub>L</sub> = 1 kΩ	2.0	50	_	175	ns
			4.5		_	35	
			6.0		_	30	
			2.0	150	_	225	ns
			4.5		_	45	
			6.0		_	38	
Output disable time	t <sub>PLZ</sub> ,t <sub>PHZ</sub>	$R_L = 1 k\Omega$	2.0	50		155	ns
			4.5		_	31	
			6.0			26	
Input capacitance	C <sub>IN</sub>					10	pF



12.9. AC Characteristics (Note) (Unless otherwise specified,  $T_a$  = -40 to 125 °C, Input:  $t_r$  =  $t_f$  = 6 ns)

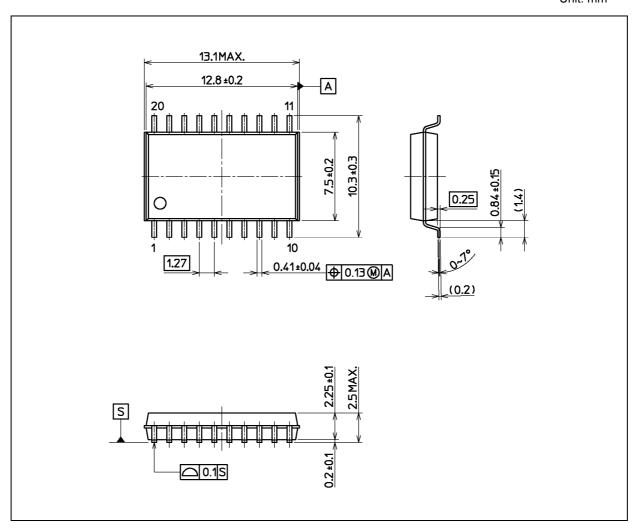
Characteristics	Symbol	Test Condition	V <sub>CC</sub> (V)	C <sub>L</sub> (pF)	Min	Max	Unit
Output transition time	t <sub>TLH</sub> ,t <sub>THL</sub>	_	2.0	50	_	85	ns
			4.5		_	17	
			6.0		_	15	
Propagation delay time	t <sub>PLH</sub> ,t <sub>PHL</sub>	_	2.0	50	_	165	ns
(LE-Q)			4.5		_	33	
			6.0		_	28	
			2.0	150	_	222	ns
			4.5		_	44	
			6.0	1	_	38	
Propagation delay time	t <sub>PLH</sub> ,t <sub>PHL</sub>	_	2.0	50	_	160	ns
(D-Q)			4.5		_	32	
			6.0		_	27	
			2.0	150	_	217	ns
			4.5		_	43	
			6.0		_	36	
Output enable time	t <sub>PZL</sub> ,t <sub>PZH</sub>	$R_L = 1 k\Omega$	2.0	50	_	198	ns
			4.5		_	40	
			6.0		_	34	
			2.0	150	_	255	ns
			4.5		_	51	
			6.0		_	43	
Output disable time	$t_{PLZ}, t_{PHZ}$	$R_L = 1 k\Omega$	2.0	50		175	ns
			4.5			35	
			6.0			29	1 l
Input capacitance	C <sub>IN</sub>	_			_	10	pF

Note: Operating Range spec of  $T_{opr}$  = -40 °C to 125 °C is applicable only for the products which manufactured after July 2020.



## **Package Dimensions**

Unit: mm



Weight: 0.51 g (typ.)

	Package Name(s)
Nickname: SOIC20	



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